DATA SHEET

74ABT16952 74ABTH16952

16-bit registered transceiver (3-State)

Product specification Supersedes data of 1995 Sep 28 IC23 Data Handbook





16-bit registered transceiver (3-State)

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FEATURES

- Two 8-bit registered transceivers
- Live insertion/extraction permitted
- Power-up 3-State
- 74ABTH16952 incorporates bus-hold data inputs which eliminate the need for external pull-up resistors to hold unused inputs
- Power-up reset
- Multiple V_{CC} and GND pins minimize switching noise
- Independent registers for A and B buses
- Output capability: +64mA/-32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs

DESCRIPTION

The 74ABT16952 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT16952 is a dual octal registered transceiver. Two 8-bit registers store data flowing in both directions between two bidirectional buses. Data applied to the inputs is entered and stored on the rising edge of the Clock (nCPXX) provided that the Clock Enable (n $\overline{\text{CEXX}}$) is Low. The data is then present at the 3-State output buffers, but is only accessible when the Output Enable (n $\overline{\text{OEXX}}$) is Low. Data flow from A inputs to B outputs is the same as for B inputs to A outputs.

Two options are available, 74ABT16952 which does not have the bus-hold feature and 74ABTH16952 which incorporates the bus-hold feature.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nCPBA to nAx or nCPAB to nBx	$C_L = 50pF; V_{CC} = 5V$	2.8 2.3	ns
C _{IN}	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	4	pF
C _{I/O}	I/O capacitance	$V_O = 0V$ or V_{CC} ; 3-State	7	pF
I _{CCZ}	Quiescent supply current	Outputs disabled; V _{CC} = 5.5V	500	μΑ
I _{CCL} Quiescent supply current		Outputs LOW; V _{CC} = 5.5V	8	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	-40°C to +85°C	74ABT16952 DL	BT16952 DL	SOT371-1
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABT16952 DGG	BT16952 DGG	SOT364-1
56-Pin Plastic SSOP Type III	-40°C to +85°C	74ABTH16952 DL	BH16952 DL	SOT371-1
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABTH16952 DGG	BH16952 DGG	SOT364-1

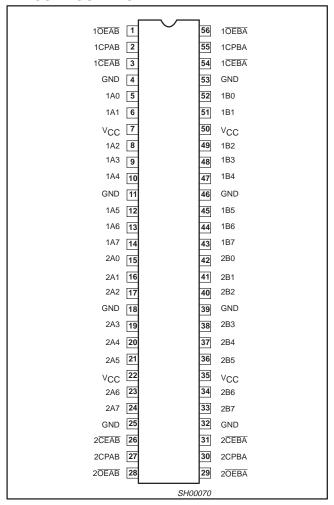
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 55 18, 22	1CPAB / 1CPBA 2CPAB / 2CPBA	Clock input A to B / Clock input B to A
3, 54, 26, 31	1CEAB / 1CEBA 2CEAB / 2CEBA	Clock enable input A to B / Clock enable input B to A
52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33	1A0 – 1A7 2A0 – 2A7	Data inputs/outputs (A side)
1, 56 8, 29	1B0 – 1B7 2B0 – 2B7	Data inputs/outputs (B side)
4, 11, 18, 25, 32, 39, 45, 53	1 <u>OEAB</u> / 1 <u>OEBA</u> 2 <u>OEAB</u> / 2 <u>OEBA</u>	Output enable inputs
4, 17, 30, 43	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

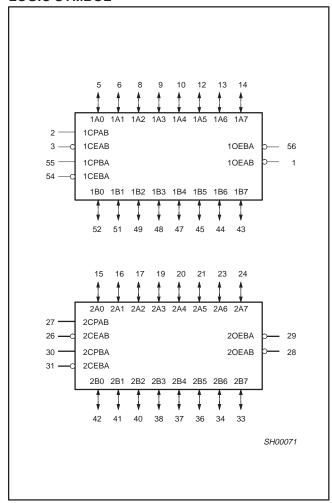
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PIN CONFIGURATION

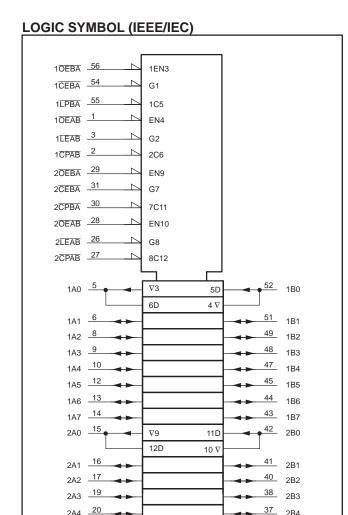


LOGIC SYMBOL



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2A5

2A6 2A7 36

2B5 34_ 2B6

2B7

SH00086

FUNCTION TABLE for Register nAx or nBx

I	NPUTS		INTERNAL	OPERATING	
nAx or nBx			Q	MODE	
Х	Х	Н	NC	Hold data	
L H	↑	L L	L H	Load data	

H = High voltage level

= Low voltage level

= Low-to-High transition

X = Don't care

XX = AB or BA

NC=No change

FUNCTION TABLE for Output Enable

INPUTS	INTERNAL	nAx or nBx	OPERATING
nOEXX	Q	OUTPUTS	MODE
Н	Х	Z	Disable outputs
L	L H	L H	Enable outputs

H = High voltage level

L = Low voltage level

X = Don't care

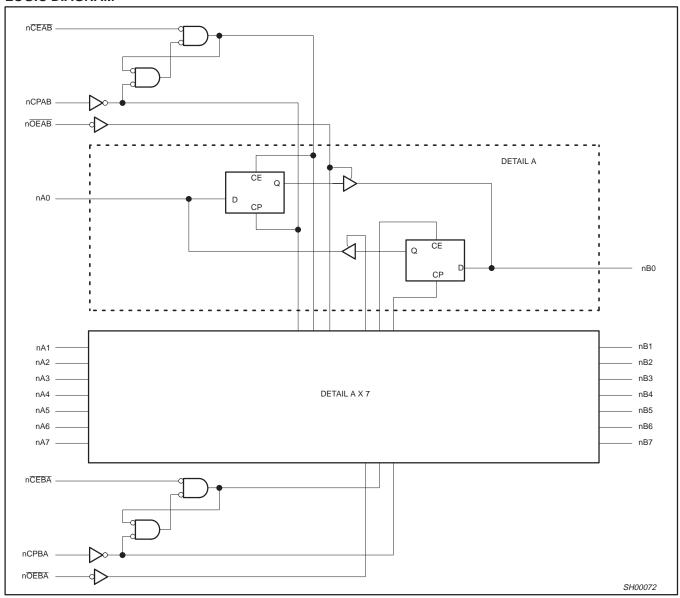
XX = AB or BA

Z = High impedance "off" state

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LOGIC DIAGRAM



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ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
lok	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +5.5	V
lau-	DC output current	Output in Low state	128	mA
Гоит		Output in High state	-64	IIIA
T _{stg}	Storage temperature range		-65 to 150	°C

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
 The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V _{CC}	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V _{CC}	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		64	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

	PARAMETER			LIMITS						
SYMBOL			TEST CONDITIONS	Tai	_{nb} = +25	5°C	T _{amb} =	: –40°C 85°C	UNIT	
				MIN	TYP	MAX	MIN	MAX	1	
V _{IK}	Input clamp volta	age	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V	
			$V_{CC} = 4.5V$; $I_{OH} = -3mA$; $V_I = V_{IL}$ or V_{IH}	2.5	2.9		2.5		V	
V_{OH}	High-level outpu	t voltage	$V_{CC} = 5.0V$; $I_{OH} = -3mA$; $V_I = V_{IL}$ or V_{IH}	3.0	3.4		3.0		V	
			$V_{CC} = 4.5V$; $I_{OH} = -32mA$; $V_I = V_{IL}$ or V_{IH}	2.0	2.4		2.0		V	
V_{OL}	Low-level output	voltage	$V_{CC} = 4.5V$; $I_{OL} = 64mA$; $V_I = V_{IL}$ or V_{IH}		0.42	0.55		0.55	V	
V _{RST}	Power-up output	low voltage ³	$V_{CC} = 5.5V$; $I_{OL} = 1mA$; $V_I = GND$ or V_{CC}		0.13	0.55		0.55	V	
I _I	Input leakage current	Control pins	$V_{CC} = 5.5V; V_I = GND \text{ or } 5.5V$		±0.01	±1.0		±1.0	μА	
			$V_{CC} = 4.5V, V_I = 0.8V$	50			50			
	Bus Hold current A inputs ⁶ 74ABTH16952		$V_{CC} = 4.5V; V_{I} = 2.0V$	-75			-75		μΑ	
			$V_{CC} = 5.5V$; $V_I = 0$ to $5.5V$	±500						
I _{OFF}	Power-off leakage current		$V_{CC} = 0V$; V_O or $V_I \le 4.5V$		±5.0	±100		±100	μΑ	
I _{PU/PD}	Power-up/down output current4	3-State	V_{CC} = 2.1V; V_O = 0.0V; V_I = GND or V_{CC} ; V_{OE} = Don't care		±5.0	±50		±50	μΑ	
I _{IH} + I _{OZH}	3-State output H	igh current	$V_{CC} = 5.5V$; $V_{O} = 5.5V$; $V_{I} = V_{IL}$ or V_{IH}		5.0	50		50	μΑ	
I _{IL} + I _{OZL}	3-State output Lo	ow current	$V_{CC} = 5.5V; V_{O} = 0.0V; V_{I} = V_{IL} \text{ or } V_{IH}$		-5.0	-50		-50	μΑ	
I _{CEX}	Output High leak	age current	V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = GND or V_{CC}		5.0	50		50	μΑ	
Io	Output current ¹		$V_{CC} = 5.5V; V_{O} = 2.5V$	-50	-70	-180	-50	-180	mA	
I _{CCH}			$V_{CC} = 5.5V$; Outputs High, $V_{I} = GND$ or V_{CC}		0.5	1.5		1.5	mA	
I _{CCL}	Quiescent supply	v current	V_{CC} = 5.5V; Outputs Low, V_I = GND or V_{CC}		8	19		19	mA	
I _{CCZ}			V_{CC} = 5.5V; Outputs 3-State; V_I = GND or V_{CC}		0.5	1.5		1.5	mA	
ΔI_{CC}	Additional supply current per input pin ² 74ABT16952		V_{CC} = 5.5V; one input at 3.4V, other inputs at V_{CC} or GND		5	100		100	μΑ	
ΔI_{CC}	Additional supply input pin ² 74ABT		V _{CC} = 5.5V; one input at 3.4V, other inputs at V _{CC} or GND		100	500		500	μА	

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

- This is the increase in supply current for each input at 3.4V.
 For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.
 This parameter is valid for any V_{CC} between 0V and 2.1V with a transition time of up to 10msec. From V_{CC} = 2.1V to V_{CC} = 5V ± 10% a transition time of up to $100\mu sec$ is permitted. 5. Unused pins at V_{CC} or GND.
- 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

 $\overline{\text{GND}} = \text{0V; } t_{\text{R}} = t_{\text{F}} = \text{2.5ns; } C_{\text{L}} = \text{50pF, } R_{\text{L}} = \text{500}\Omega$

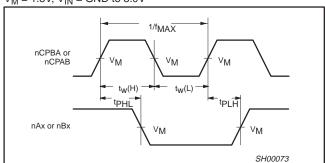
			LIMITS					
SYMBOL	PARAMETER	WAVEFORM	T _{amb} = +25°C V _{CC} = +5.0V			$T_{amb} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = +5.0\text{V } \pm 0.5\text{V}$		UNIT
			MIN	TYP	MAX	MIN	MAX	
f _{MAX}	Maximum clock frequency	1	150			150		MHz
t _{PLH} t _{PHL}	Propagation delay nCPBA to nAx, nCPAB to nBx	1	1.0 1.0	2.8 2.3	3.9 3.9	1.0 1.0	4.3 4.3	ns
t _{PZH}	Output enable time nOEBA to nAx, nOEAB to nBx	3 4	1.0 1.0	2.5 2.2	3.8 3.8	1.0 1.0	4.6 4.6	ns
t _{PHZ} t _{PLZ}	Output disable time nOEBA to nAx, nOEAB to nBx	3 4	1.7 1.3	3.4 2.6	4.4 3.9	1.7 1.3	5.2 4.2	ns

AC SETUP REQUIREMENTS

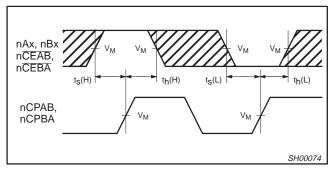
SYMBOL	PARAMETER	WAVEFORM	T _{amb} = +25°C V _{CC} = +5.0V		T_{amb} = -40°C to +85°C V_{CC} = +5.0V ±0.5V	UNIT
			MIN	TYP	MIN	1
t _S (H) t _s (L)	Setup time nAx to nCPAB or nBx to nCPBA	2	1.2 1.5	0.9 1.2	1.2 1.5	ns
t _h (H) t _h (L)	Hold time nAx to nCPAB or nBx to nCPBA	2	0.0 0.0	-1.2 -0.9	0.0 0.0	ns
t _s (H) t _s (L)	Setup time nCEAB to nCPAB, nCEBA to nCPBA	2	1.2 1.6	0.9 1.1	1.2 1.6	ns
t _h (H) t _h (L)	Hold time nCEAB to nCPAB, nCEBA to nCPBA	2	0.0 0.0	-1.1 -0.9	0.0 0.0	ns
t _w (H) t _w (L)	nCPAB or nCPBA pulse width, High or Low	1	3.3 2.5	2.6 1.0	3.3 2.5	ns

AC WAVEFORMS

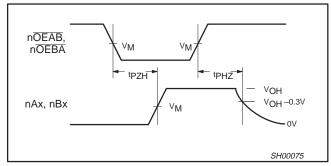
 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$



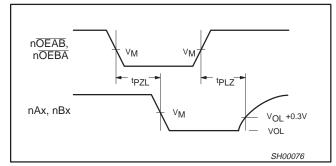
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



Waveform 2. Data Setup and Hold Times



Waveform 3. 3-State Output Enable Time to High Level and Output Disable Time from High Level

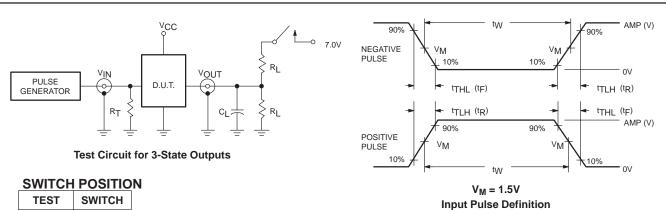


Waveform 4. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

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TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PLZ}	closed
t _{PZL}	closed
All other	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

$$\begin{split} R_T = & \text{ Termination resistance should be equal to } Z_{OUT} \text{ of } \\ & \text{ pulse generators.} \end{split}$$

FAMILY	INPUT PULSE REQUIREMENTS							
FAMILY	Amplitude	Rep. Rate	t _W	t _R	t _F			
74ABT/H16	3.0V	1MHz	500ns	2.5ns	2.5ns			

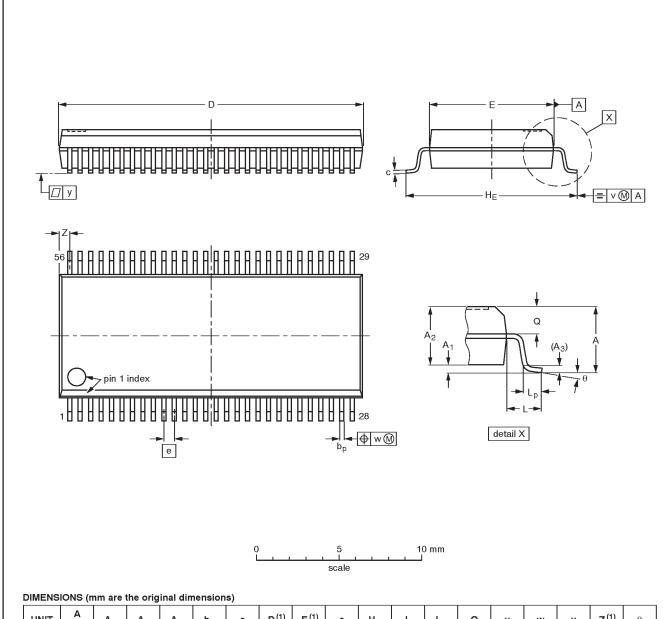
SA00018

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SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1



UNIT	A max.	Α ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	18.55 18.30	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT371-1		MO-118AB				93-11-02 95-02-04

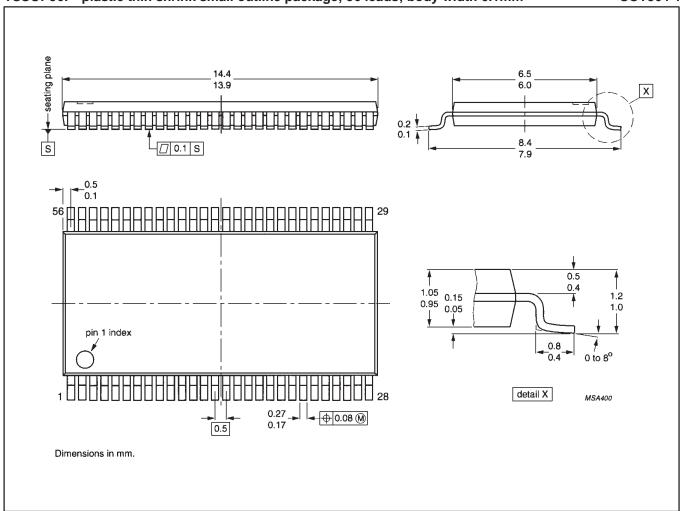
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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm

SOT364-1



16-bit registered transceiver (3-State)

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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